

## Diode Module

Type : YZPST-SKKE600/16

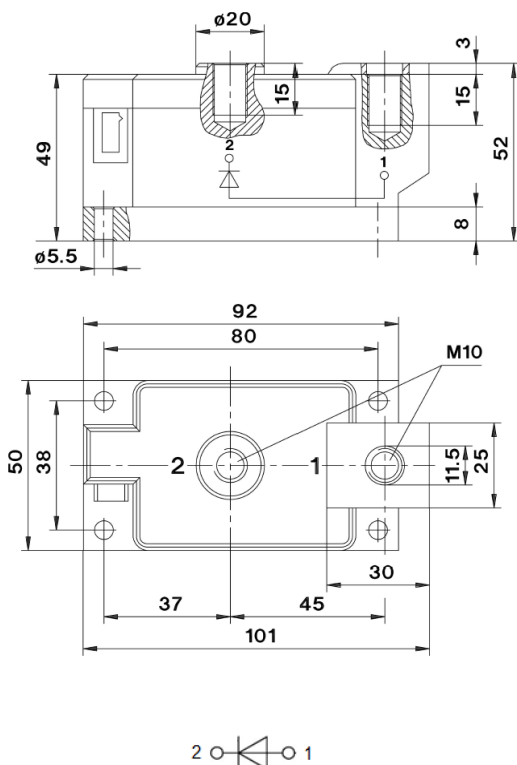
### Absolute Maximum Ratings

Symbol	Condition	Ratings	Unit
$V_{RRM}$	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj \text{ max}}$	1600	V
$V_{RSM}$	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj \text{ max}}$	$V_{RRM} + 100$	V
$I_{F(RMS)}$	$T_c = 100^{\circ}\text{C}$	930	A
$I_{F(AV)}$	$T_c = 100^{\circ}\text{C}$	600	A
$I_{FSM}$	50 Hz, 60% $V_{RRM}$ reapplied, $T_j = 150^{\circ}\text{C}$	18	KA
$I^2t$	50 Hz, 60% $V_{RRM}$ reapplied, $T_j = 150^{\circ}\text{C}$	1805	KA <sup>2</sup> S
$V_{iso}$	50 Hz, A.C. 1s / 1min.	3600/3000	V
$T_j$		-40 ~ +150	$^{\circ}\text{C}$
$T_{stg}$		-40 ~ +130	$^{\circ}\text{C}$
M1	Busbar, Tolerance of $\pm 15\%$	5	Nm
M2	to heatsink, Tolerance of $\pm 10\%$	17	Nm
W	About	940	g

### Electrical Characteristics/Thermal Characteristics

Symbol	Condition	Ratings	Unit
$I_{RRM}$	Up to $V_{RRM}$ , $T_j = 150^{\circ}\text{C}$	15	mA
$V_F$	$I_F = 3000\text{A}$ , $T_j = 25^{\circ}\text{C}$	1.5	V
$V_{(TO)}$	$T_j = 150^{\circ}\text{C}$	0.75	V
$r_T$	$T_j = 150^{\circ}\text{C}$	0.25	m $\Omega$
$R_{th(j-c)}$	Per Junction, both conducting	0.07	K/W
$R_{th(c-s)}$	Per Module	0.02	K/W

### Case Outline And Dimensions



### Features:

- Pressure contact technology for high reliability
- Advanced Medium Power Technology (AMPT)
- Industrial standard package
- Electrically insulated base plate

### Applications:

- Rectifier for drives applications
- Rectifiers for UBS
- Battery chargers